## NSN 5961-01-285-6683

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Inclosure Material:

Metal

**Overall Length:** 

Between 0.970 inches and 1.218 inches

**Mounting Facility Quantity:** 

1

**Internal Configuration:** 

Junction contact

**Electrode Internally-electrically Connected To Case:** 

Collector

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Quality assurance level txv

**Overall Width Across Flats:** 

Between 0.423 inches and 0.438 inches

**Thread Size:** 

0.190 inches

**Semiconductor Material:** 

Silicon

Voltage Rating In Volts Per Characteristic:

110.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open

**Current Rating Per Characteristic:** 

5.00 amperes zero-gate-voltage source current blank

**Power Rating Per Characteristic:** 

2.0 watts small-signal input power, common-collector preset

**Maximum Operating Tempurature Per Measurement Point:** 

200.0 degrees celsius junction

**Special Features:** 

Junction pattern arrangement: npn

**Test Data Document:** 

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

**Thread Series Designator:** 

Unf

**Terminal Type And Quantity:** 

1 wire hook and 2 tab, solder lug

**Specification Data:** 

81349-mil-s-19500/315 government specification

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

A110a0